

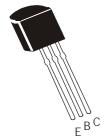
#### Continental Device India Limited

An ISO/TS 16949 and ISO 9001 Certified Manufacturer



## NPN SILICON PLANAR EPITAXIAL TRANSISTORS

CN650 / CN651



TO-92 Plastic Package

## Complementary CP750 and CP751

Use in Wide Variety of Industrial and Consumer Applications Including Lamp and Solenoid Drivers and Audio Amplifier

### ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

DESCRIPTION	SYMBOL	CN650	CN651	UNIT	
Collector Base Voltage	$V_{CBO}$	60	80	V	
Collector Emitter Voltage	$V_{\sf CEO}$	45	60	V	
Emitter Base Voltage	$V_{EBO}$	5	5		
Peak Pulse Current	*I <sub>CM</sub>	6	6		
Collector Current Continuous	I <sub>C</sub>	2		Α	
Power Dissipation @ T <sub>a</sub> =25°C	$P_{D}$	0.9	0.9		
Derate Above 25°C		7.2		mW/ºC	
Power Dissipation @ T <sub>a</sub> =25°C	**P <sub>D</sub>	1.1		W	
Power Dissipation @ T <sub>C</sub> =25°C	$P_{D}$	2.2	W		
Operating and Storage Junction Temperature Range	$T_{j},T_{stg}$	- 65 to -	<b>+</b> 150	∘C	

#### **Thermal Resistance**

Junction to Ambient	R <sub>th (j-a) 1</sub>	138.8	°C/W
Junction to Ambient	R <sub>th (j-a) 2+</sub>	113.6	°C/W
Junction to Case	R <sub>th (j-c)</sub>	56.8	°C/W

<sup>\*</sup> Consult safe operating area graph for conditions.

#### **ELECTRICAL CHARACTERISTICS (T<sub>a</sub>=25°C unless specified otherwise)**

DESCRIPTION	SYMBOL	TEST CONDITION		MIN	MAX	UNIT
Collector Base Voltage	$V_{CBO}$	$I_{C}=100\mu A, I_{E}=0$	CN650	60		V
			CN651	80		V
Collector Emitter Voltage	$V_{CEO}$	$I_C=1$ mA, $I_B=0$	CN650	45		V
			CN651	60		V
Emitter Base Voltage	$V_{EBO}$	$I_E=100\mu A, I_C=0$		5.0		V
Collector Cut Off Current	I <sub>CBO</sub>	$V_{CB} = 45V, I_{E} = 0$	CN650		100	nA
		$V_{CB}=45V, I_{E}=0, T_{a}=100^{\circ}$	°C		10	μΑ
		$V_{CB} = 60V, I_{E} = 0$	CN651		100	nA
		$V_{CB}=60V$ , $I_{E}=0$ , $T_{a}=100^{\circ}$	°C		10	μΑ
Emitter Cut Off Current	I <sub>EBO</sub>	$V_{EB}=4V$ , $I_C=0$			100	nA

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<sup>\*\*</sup>Transistors mounted on printed circuit board. Lead Length 4mm, mounting pad for collector lead min 10mm x 10 mm, copper

<sup>2+</sup> Device mounted on P.C.B with copper equal to 1sq.inch. minimum



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# **ELECTRICAL CHARACTERISTICS (T<sub>a</sub>=25°C unless specified otherwise)**

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNIT
Collector Emitter Saturation Voltage	*** V <sub>CE (sat)</sub>	I <sub>C</sub> =1A, I <sub>B</sub> =100mA		0.3	V
		I <sub>C</sub> =2A, I <sub>B</sub> =200mA		0.5	V
Base Emitter Saturation Voltage	***V <sub>BE (sat)</sub>	I <sub>C</sub> =1A, I <sub>B</sub> =100mA		1.25	V
Base Emitter on Voltage	*** V <sub>BE (on)</sub>	I <sub>C</sub> =1A, V <sub>CE</sub> =2V		1.0	V
DC Current Gain	*** h <sub>FE</sub>	I <sub>C</sub> =50mA,V <sub>CE</sub> =2V	70		
		$I_C=500$ mA, $V_{CE}=2$ V	100	300	
		I <sub>C</sub> =1A, V <sub>CE</sub> =2V	80		
		$I_C=2A$ , $V_{CE}=2V$	40		
Transition Frequency	f⊤	I <sub>C</sub> =100mA, V <sub>CE</sub> =5V, f=100MHz	140		MHz
Output Capacitance	$C_{obo}$	$V_{CB}=10V$ , $I_{E}=0$ , $f=1MHz$		30	pF

#### **SWITCHING TIMES**

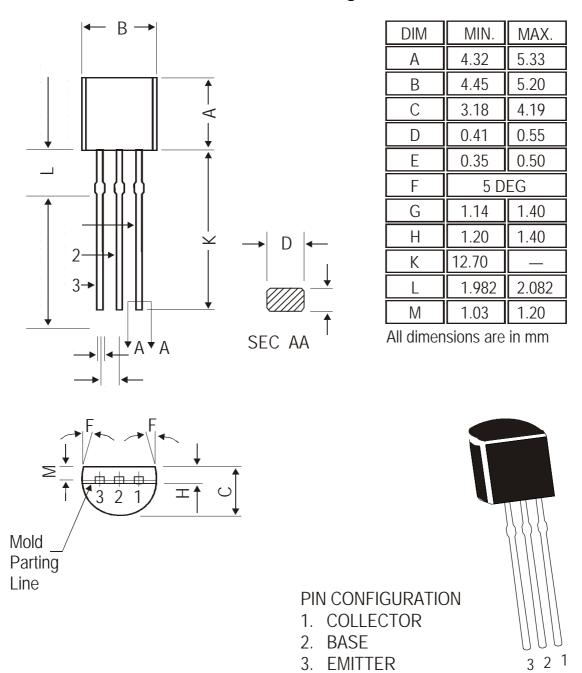
DESCRIPTION	SYMBOL	TEST CONDITION	TYP	UNIT
Turn On Time	t <sub>on</sub>	$I_C$ =500mA, $I_{B1}$ =50mA	45	ns
Turn Off Time	t <sub>off</sub>	$I_{B2}$ =50mA, $V_{CC}$ =10V	800	ns

<sup>\*\*\*</sup>Measured under Pulse Conditions. Pulse Width=300ms. Duty Cycle\_2%

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## **TO-92 Plastic Package**



The TO-92 Package, Tape and Ammo Pack Drawings are correct as on the date of issue/revision of this Data Sheet.

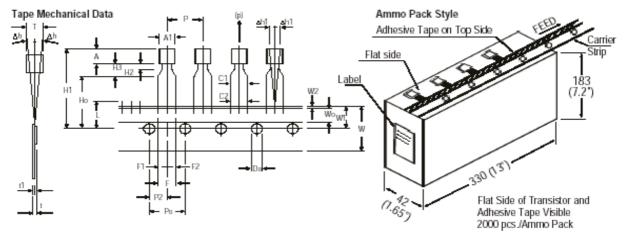
The currently valid dimensions and information, may please be confirmed from the TO-92 Drawing in the Packages and Packing Section of the Product Catalogue.

# **Packing Details**

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PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Oty	Size Oty		Size Oty Gr		Gr Wt
TO-92 Bulk	1K/polybag	200 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	23 kgs
TO-92 T&A	2K/ammo box	645 gm/2K pcs	12.5" x 8" x 1.8"	2K	17" x 15" x 13.5"	32K	12.5 kgs

# **TO-92 Plastic Package**

# TO-92 Tape and Ammo Pack



#### All dimensions are in mm

		SPECIFICATION			ION	
ITEM	SYMBOL	MIN.	NOM.	MAX.	TOL.	
BODY WIDTH	A1	4.45		5.20		NOTES
BODY HEIGHT	Α	4.32		5.33		Maximum alignment deviation between
BODY THICKNESS	T	3.18		4.19		leads will not to be greater than 0.2m
PITCH OF COMPONENT	Р		12.7		± 1.0	2. Maximum non-cumulative variation
*1FEED HOLE PITCH	Po		12.7		± 0.3	between tape feed holes shall not
*2 FEED HOLE CENTRE TO						exceed 1 mm in 20 pitches.
COMPONENT CENTRE	P2		6.35		± 0.4	<ol><li>Holddown tape will not exceed beyon</li></ol>
DISTANCE BETWEEN OUTER	_		5.08		+ 0.6	the edge(s) of carrier tape and there
LEADS	F		5.08		- 0.2	shall be no exposure of adhesive.
*3 COMPONENT ALIGNMENT SIDE VIEW	Δh		0	1.0		There will be no more than three (3)
*4 COMPONENT ALIGNMENT FRONT VIEW	∆h1		0	1.3		consecutive missing components in a
TAPE WIDTH	W		18		± 0.5	tape.
HOLD-DOWN TAPE WIDTH	Wo		6		± 0.2	A tape trailer, having at least three fer     below are provided after the last
HOLE POSITION	W1		9		+ 0.7	holes are provided after the last component in a tape.
					- 0.5	· · · · · ·
HOLD-DOWN TAPE POSITION	W2	0.0		0.7		<ol><li>Splices should not interfere with the sprocket feed holes.</li></ol>
LEAD WIRE CLINCH HEIGHT	Ho		16		± 0.5	sprocket leed notes.
COMPONENT HEIGHT	H1			24.0		
LENGTH OF SNIPPED LEADS	L			11.0		
FEED HOLE DIAMETER	Do		4		± 0.2	REMARKS
*5 TOTAL TAPE THICKNESS	t			1.2		*1 Cumulative pitch error 1.0 mm/20 pit
LEAD - TO - LEAD DISTANCE	F1, F2	2.40		2.70	- 0.1	
STAND OFF	H2	0.45		1.45	- 0.1	*2 To be measured at bottom of clinch
CLINCH HEIGHT	H3			3.0		*3 At top of body
LEAD PARALLELISM	C1 - C2			0.22		*4 At top of body
PULL - OUT FORCE	(p)	6N				*5 t1 0.3 – 0.6 mm

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- ond
- а
- eed
- itch

Customer Notes CN650 / CN651

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#### **Disclaimer**

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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